NSN 5961-01-192-7381



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-192-7381 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.165 inches **Overall Height:** 0.200 inches **Overall Width:** 0.325 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open all transistor and 60.0 collector to base voltage, dc all transistor and 5.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 50.00 microamperes zero-gate-voltage source current preset all transistor **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter all transistor and 100.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Internal junction configuration transistor npn **Terminal Type And Quantity:** 14 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: